

Enhancing Efficiency and Stability in 2D/3D Hybrid Perovskite Solar Cells: A Simulation Study of N-I-P and P-I-N Architectures with Different Charge Transport Layers.

L.A David-Egbunu^{1,2*}, Z.Z Tshobeni², W.Fidel², J.Botsoa², N.Doumit¹, E.Ntsoenzok², L.Trojman¹

*LISITE, Institut supérieur d'électronique de Paris (ISEP), 92130 Issy-les-Moulineaux, France, lilian.david-egbunu@ext.isep.fr,

¹ LISITE, Institut supérieur d'électronique de Paris (ISEP), 92130 Issy-les-Moulineaux, France. nicole.doumit@isep.fr, lionel.trojman@isep.fr

² CEHMTI, Centre national de la recherche scientifique (CNRS), 45071, Orléans, France. ziyanda.tshobeni@cnrs-orleans.fr, wisly.fidel@cnrs-orleans.fr, jacques.botsoa@cnrs-orleans.fr, esidor.ntsoenzok@cnrs-orleans.fr

Abstract:

Perovskite solar cells (PSCs) have achieved power conversion efficiencies (PCEs) exceeding 25% for single-junction devices, making them a promising low-cost photovoltaic technology. However, their long-term stability under environmental conditions remains a challenge to commercialization [1,2]. To address this, researchers have been studying 2D/3D hybrid perovskite structures, which combine the efficiency of 3D perovskites with the improved stability of 2D layers [3]. In our previous study, we used QuantumATK to investigate the intrinsic properties of the 2D/3D interface of (BA₂FAPb₂I₇/FAPbI₃) hybrid Perovskite, which showed optimal band alignment, facilitating efficient charge transfer, and enhanced light absorption.

However, optimizing device architectures and material selections remains critical to overcoming stability challenges and moving into commercialization. In this study, we investigate the performance and stability of the FAPbI₃/BA₂FAPb₂I₇ hybrid perovskite solar cell in both n-i-p and p-i-n device architectures using SCAPS-1D. We tested a combination of five electron transport layers (ETLs)—TiO₂, SnO₂, ZnO, IGZO, and In₂O₃:Zn—and five hole transport layers (HTLs)—Spiro-OMeTAD, CuSCN, NiOx, CuI, and PEDOT:PSS. This resulted in fifty different device configurations.

Our results show that the p-i-n structure performs better overall, achieving a higher open-circuit voltage, short-circuit current, and device efficiency, compared to the n-i-p structure. We further analysed the three best performing structures by varying absorber and ETL thickness, series and shunt resistance, and operating temperature. The obtained results from SCAPS-1D will be used in fabricating 2D/3D heterostructure perovskite solar cells (PSCs) for our future work.

References

- [1] Q. Jiang et al., "Achievements, challenges, and future prospects for industrialization of perovskite solar cells," *Light: Science & Applications*, vol. 13, no. 1, 2024. DOI: [10.1038/s41377-024-01461-x](https://doi.org/10.1038/s41377-024-01461-x)
- [2] S. S. Kalpathi et al., "Perovskite solar cells: Progress, challenges, and future avenues to clean energy," *Solar Energy Materials and Solar Cells*, vol. 267, 2024. DOI: [10.1016/j.solmat.2024.112900](https://doi.org/10.1016/j.solmat.2024.112900)
- [3] Y. Lin et al., "Recent progress in the development of high-efficiency inverted perovskite solar cells," *NPG Asia Materials*, vol. 15, no. 1, 2023. DOI: [10.1038/s41427-023-00474-z](https://doi.org/10.1038/s41427-023-00474-z)